### INTEGRATED CIRCUITS

# DATA SHEET



# 74LV4053

Triple 2-channel analog multiplexer/demultiplexer

Product specification Supersedes data of 1997 Jul 15 IC24 Data Handbook





# Triple 2-channel analog multiplexer/demultiplexer

74LV4053

#### **FEATURES**

- Optimized for low voltage applications: 1.0 to 6.0 V
- Accepts TTL input levels between V<sub>CC</sub> = 2.7 V and V<sub>CC</sub> = 3.6 V
- Low typ "ON" resistance:

100  $\Omega$  at V<sub>CC</sub> – V<sub>EE</sub> = 4.5 V 150  $\Omega$  at V<sub>CC</sub> – V<sub>EE</sub> = 3.0 V 240  $\Omega$  at V<sub>CC</sub> – V<sub>EE</sub> = 2.0 V

- Logic level translation: to enable 3 V logic to communicate with ± 3 V analog signals
- Typical "break before make" built in
- Output capability: non-standard
- I<sub>CC</sub> category: MSI

#### DESCRIPTION

The 74LV4053 is a low-voltage CMOS device and is pin and function compatible with the 74HC/HCT4053.

The 74LV4053 is a triple 2-channel analog multiplexer/demultiplexer with a common enable input (Ē). Each multiplexer/demultiplexer has two independent inputs/outputs ( $nY_0$  to  $nY_1$ ), a common input/output (nZ) and three digital select inputs (S<sub>1</sub> to S<sub>3</sub>).

With  $\overline{\mathsf{E}}$  LOW, one of the two switches is selected (low impedance ON-state) by S<sub>1</sub> to S<sub>3</sub> With  $\overline{E}$  HIGH, all switches are in the high impedance OFF-states, independent of S<sub>1</sub> and S<sub>3</sub>.

V<sub>CC</sub> and GND are the supply voltage pins for the digital control inputs (S<sub>1</sub>, to S<sub>3</sub>, and  $\overline{E}$ ). The V<sub>CC</sub> to GND ranges are 1.0 to 6.0 V. The analog inputs/outputs (nY<sub>0</sub>, to nY<sub>1</sub>, and nZ) can swing between V<sub>CC</sub> as a positive limit and  $V_{EE}$  as a negative limit.  $V_{CC}$  -  $V_{EE}$  may not exceed 6.0 V. For operation as a digital multiplexer/demultiplexer,  $V_{EE}$ is connected to GND (typically ground).

#### **QUICK REFERENCE DATA**

GND = 0 V;  $T_{amb} = 25^{\circ}C$ ;  $t_r = t_f \le 2.5 \text{ ns}$ 

GND = 0 V; T	$t_{amb} = 25^{\circ}C; t_{r} = t_{f} \le 2.5 \text{ ns}$	43_		
SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t <sub>PZH</sub> /t <sub>PZL</sub>	Turn "ON" time E to V <sub>OS</sub> S <sub>n</sub> to V <sub>OS</sub>	$\begin{array}{c} C_L = 15 \text{ pF} \\ R_L = 1 \text{K}\Omega \\ V_{CC} = 3.3 \text{ V} \end{array}$	16 20	ns
t <sub>PHZ</sub> /t <sub>PLZ</sub>	Turn "OFF" time E to V <sub>OS</sub> S <sub>n</sub> to V <sub>OS</sub>	Com	17 16	115
C <sub>I</sub>	Input capacitance		3.5	
C <sub>PD</sub>	Power dissipation capacitance per switch	See Notes 1 and 2	36	pF
C <sub>S</sub>	Maximum switch capacitance independent (Y) common (Z)		5 8	

#### NOTES:

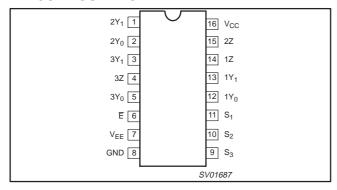
- $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ )

  - $$\begin{split} &P_D = C_{PD} \times V_{CC}{}^2 \times f_i + {}^{\sum} \left( (C_{L} + C_S) \times V_{CC}{}^2 \times f_o \right) \text{ where:} \\ &f_i = \text{input frequency in MHz; } C_L = \underset{}{\text{output load capacity in pF;}} \\ &f_o = \text{output frequency in MHz; } C_S = \underset{}{\text{maximum switch capacitance in pF;}} \end{split}$$
- $V_{CC}$  = supply voltage in V;  $\sum ((C_L + C_S) \times V_{CC}^2 \times f_o)$  = sum of the outputs. The condition is  $V_I$  = GND to  $V_{CC}$ .

#### ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	PKG. DWG. #
16-Pin Plastic DIL	-40°C to +125°C	74LV4053 N	74LV4053 N	SOT38-1
16-Pin Plastic SO	-40°C to +125°C	74LV4053 D	74LV4053 D	SOT109-1
16-Pin Plastic SSOP Type II	-40°C to +125°C	74LV4053 DB	74LV4053 DB	SOT338-1
16-Pin Plastic TSSOP Type I	-40°C to +125°C	74LV4053 PW	74LV4053PW DH	SOT403-1

#### **PIN CONFIGURATION**



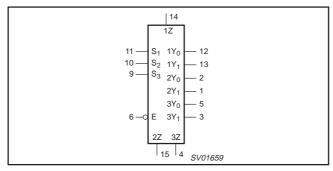
#### PIN DESCRIPTION

PIN NUMBER	SYMBOL	FUNCTION			
2, 1	2Y <sub>0</sub> , 2Y <sub>1</sub>	Independent inputs/outputs			
5, 3	3Y <sub>0</sub> , 3Y <sub>1</sub>	Independent inputs/outputs			
6	Ē	Enable input (active LOW)			
7	V <sub>EE</sub>	Negative supply voltage			
8	GND	Ground (0 V)			
11, 10, 9	S <sub>1</sub> to S <sub>3</sub>	Select inputs			
12, 13	1Y <sub>0</sub> , 1Y <sub>1</sub>	Independent inputs/outputs			
14, 15, 4	1Z to 3Z	Common inputs/outputs			
16	V <sub>CC</sub>	Positive supply voltage			

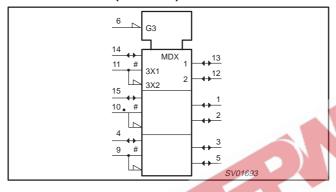
# Triple 2-channel analog multiplexer/demultiplexer

74LV4053

#### **LOGIC SYMBOL**



#### LOGIC SYMBOL (IEEE/IEC)



#### **FUNCTION TABLE**

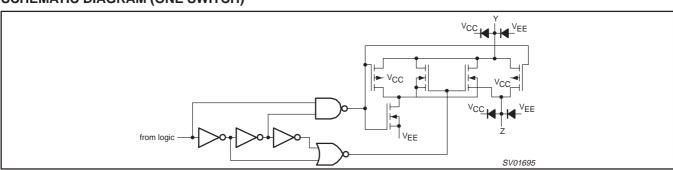
INP	UTS	CHANNEL		
Ē	Sn	ON		
L	L	nY <sub>0</sub> – nZ		
L	Н	nY <sub>1</sub> – nZ		
Н	X	None		

#### NOTES:

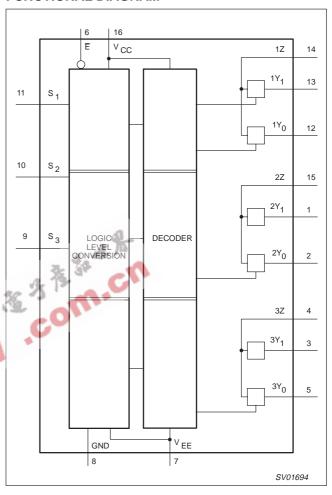
H = HIGH voltage level L = LOW voltage level

X = don't care

### **SCHEMATIC DIAGRAM (ONE SWITCH)**



#### **FUNCTIONAL DIAGRAM**



# Triple 2-channel analog multiplexer/demultiplexer

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#### **ABSOLUTE MAXIMUM RATINGS<sup>1, 2</sup>**

In accordance with the Absolute Maximum Rating System (IEC 134). Voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V <sub>CC</sub>	DC supply voltage		-0.5 to +7.0	V
± I <sub>IK</sub>	DC input diode current	$V_{I} < -0.5 \text{ or } V_{I} > V_{CC} + 0.5 \text{ V}$	20	mA
±I <sub>SK</sub>	DC switch diode current	$V_{O} < -0.5 \text{ or } V_{O} > V_{CC} + 0.5 \text{ V}$	20	mA
±IS	DC switch current	$-0.5 \text{ V} < \text{V}_{\text{S}} < \text{V}_{\text{CC}} + 0.5 \text{ V}$	25	mA
T <sub>stg</sub>	Storage temperature range		-65 to +150	°C
Ртот	Power dissipation per package  – plastic DIL  – plastic mini-pack (SO)  – plastic shrink mini-pack (SSOP and TSSOP)	for temperature range: –40 to +125°C above +70°C derate linearly with 12 mW/K above +70°C derate linearly with 8 mW/K above +60°C derate linearly with 5.5 mW/K	750 500 400	mW

#### NOTES

#### **RECOMMENDED OPERATING CONDITIONS**

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
V <sub>CC</sub>	DC supply voltage	See Note 1 and Figure 5	1.0	3.3	6.0	V
VI	Input voltage	Co	0	_	V <sub>CC</sub>	V
Vo	Output voltage		0	_	V <sub>CC</sub>	V
T <sub>amb</sub>	Operating ambient temperature range in free air	See DC and AC characteristics	-40 -40		+85 +125	°C
t <sub>r</sub> , t <sub>f</sub>	Input rise and fall times	$V_{CC} = 1.0 \text{ V to } 2.0 \text{ V}$ $V_{CC} = 2.0 \text{ V to } 2.7 \text{ V}$ $V_{CC} = 2.7 \text{ V to } 6.0 \text{ V}$	- - -	- - -	500 200 100	ns/V

#### NOTE:

Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the
device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to
absolute-maximum-rated conditions for extended periods may affect device reliability.

<sup>2.</sup> The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

<sup>1.</sup> The LV is guaranteed to function down to  $V_{CC} = 1.0 \text{V}$  (input levels GND or  $V_{CC}$ ); DC characteristics are guaranteed from  $V_{CC} = 1.2 \text{V}$  to  $V_{CC} = 6.0 \text{V}$ .

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### DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions, voltages are referenced to GND (ground = 0 V)

						LIMITS			╛
SYMBOL	PARAMETER	TEST CO	ONDITIONS	-4	0°C to +8	5°C	-40°C to	o +125°C	UNIT
				MIN	TYP <sup>1</sup>	MAX	MIN	MAX	1
		V <sub>CC</sub> = 1.2 V		0.9			0.9		
	l <u>-</u>	V <sub>CC</sub> = 2.0 V		1.4			1.4		1
$V_{IH}$	HIGH level Input voltage	V <sub>CC</sub> = 2.7 to 3.6 V		2.0			2.0		V
	Voltage	V <sub>CC</sub> = 4.5 V		3.15			3.15		1
		V <sub>CC</sub> = 6.0 V		4.20			4.20		1
		V <sub>CC</sub> = 1.2 V				0.3		0.3	
		V <sub>CC</sub> = 2.0 V				0.6		0.6	1
$V_{IL}$	LOW level Input voltage	$V_{CC} = 2.7 \text{ to } 3.6 \text{ V}$				0.8		0.8	<b>1</b> v
	voitage	V <sub>CC</sub> = 4.5 V				1.35		1.35	1
		V <sub>CC</sub> = 6.0 V				1.80		1.80	1
	Input leakage	V <sub>CC</sub> = 3.6			-	1.0		1.0	١.
$\pm l_1$	current	$V_{CC} = 6.0$	$V_I = V_{CC}$ or GND		4 - 35	2.0		2.0	μA
	Analog switch	V <sub>CC</sub> = 3.6	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>	. 3%	120	1.0		1.0	+
±Is	OFF-state current		$-  V_S  = V_{CC} - GND$	3	-	1.0		1.0	μΑ
Ü	per channel	$V_{CC} = 6.0$	(See Figure 2)		40.	2.0		2.0	'
	Analog switch	V <sub>CC</sub> = 3.6	$V_I = V_{IH}$ or $V_{IL}$	C		1.0		1.0	
±Is	ON-state current	V <sub>CC</sub> = 6.0	$V_{S}I = V_{CC} - GND$ (See Figure 3)			2.0		2.0	μΑ
	Quiescent supply	V <sub>CC</sub> = 3.6 V	$V_I = V_{CC}$ or GND			20.0		40	
Icc	current $V_{CC} = 6.0 \text{ V}$		$V_{IS} = GND \text{ or } V_{CC};$ $V_{OS} = V_{CC} \text{ or } GND$			40.0		80	μΑ
Δl <sub>CC</sub>	Additional quiescent supply	$V_{CC} = 2.7 \text{ to } 3.6 \text{ V}$	$V_{I} = V_{CC} - 0.6 \text{ V}$			500		850	μΑ
	current per input		1 100 1		_				₩
		V <sub>CC</sub> = 1.2 V	$\begin{split} I_S &= 100 \; _{\mu}A; \\ V_{IS} &= V_{CC} \; to \; GND; \\ V_I &= V_{IH} \; or \; V_{IL} \end{split}$						
	ON-resistance	V <sub>CC</sub> = 2.0 V			180	365		435	1
$R_{ON}$	(peak)	V <sub>CC</sub> = 2.7 V	I <sub>S</sub> = 1000 <sub>μ</sub> A;		115	225		270	Ω
	,	$V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$	$V_{IS} = V_{CC}$ to GND;		100	200		245	
		V <sub>CC</sub> = 4.5 V	$V_I = V_{IH} \text{ or } V_{IL}$		75	150		180	
		V <sub>CC</sub> = 6.0 V	7		70	140		165	1
		V <sub>CC</sub> = 1.2 V	$I_S = 100 \mu A;$ $V_{IS} = GND;$ $V_I = V_{IH} \text{ or } V_{IL}$		250				
	ON-resistance	V <sub>CC</sub> = 2.0 V			120	280		325	1
$R_{ON}$	(rail)	V <sub>CC</sub> = 2.7 V	$I_{S} = 1000  \mu A;$		75	170		195	Ω
		$V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$	$V_{IS} = GND;$		70	155		180	1
		V <sub>CC</sub> = 4.5 V	$V_I = V_{IH}$ or $V_{IL}$		50	120		135	1
		V <sub>CC</sub> = 6.0 V	┪		45	105		120	1
		V <sub>CC</sub> = 1.2 V	$V_{I} = V_{IH} \text{ or } V_{IL};$ $I_{S} = 100 _{\mu}A;$ $V_{IS} = V_{CC}$		350				
	l	V <sub>CC</sub> = 2.0 V	10 - 00		170	340		400	1
$R_{ON}$	ON-resistance (rail)	$V_{CC} = 2.7 \text{ V}$	$\dashv$		105	210		250	Ω
J.11	(raii)	$V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$ $V_{I} = 3.0 \text{ to } 3.6 \text{ V}$	$V_I = V_{IH} \text{ or } V_{IL};$ $I_S = 1000 \mu A;$		95	190		225	┨
		$V_{CC} = 3.0 \text{ to } 3.0 \text{ V}$ $V_{CC} = 4.5 \text{ V}$	$V_{IS} = V_{CC}$		70	140		165	┨
		$V_{CC} = 4.3 \text{ V}$ $V_{CC} = 6.0 \text{ V}$	-		65	125		150	$\dashv$
		ACC - 0.0 A			00	120		150	

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#### DC ELECTRICAL CHARACTERISTICS (Continued)

SYMBOL PARAMETER		TEST CONDI	-40	0°C to +85	i°C	-40°C to	UNIT		
			MIN	TYP <sup>1</sup>	MAX	MIN	MAX		
		V <sub>CC</sub> = 1.2 V							
	Maximum variation	$V_{CC} = 2.0 \text{ V}$			5				
ΔR <sub>ON</sub>	of ON-resistance	$V_{CC} = 2.7 \text{ V}$	<sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; <sub>IS =</sub> V <sub>CC</sub> to GND		4				Ω
ANON	between any two	$V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$	$_{IS} = V_{CC}$ to GND		4				52
	channels	V <sub>CC</sub> = 4.5 V			3				
		$V_{CC} = 6.0 \text{ V}$			2				

#### NOTES:

- All typical values are measured at T<sub>amb</sub> = 25°C. At supply voltages approaching 1.2 V, the analog switch ON-resistance becomes extremely non-linear. Therefore, it is recommended that these devices be used to transmit digital signals only, when using these supply voltages.

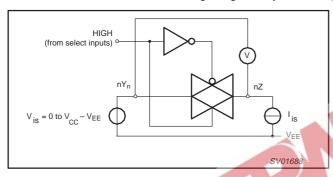


Figure 1. Test circuit for measuring ON-resistance (R<sub>ON</sub>).

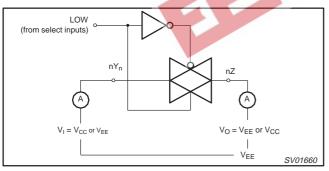


Figure 2. Test circuit for measuring OFF-state current.

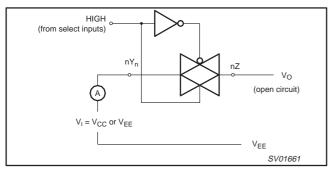


Figure 3. Test circuit for measuring ON-state current.

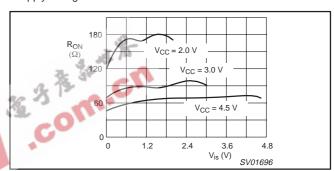


Figure 4. Typical ON-resistance ( $R_{on}$ ) as a function of input voltage ( $V_{is}$ ) for  $V_{is} = 0$  to  $V_{CC} - V_{EE}$ .

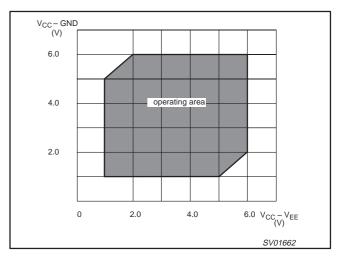


Figure 5. Guaranteed operating area as a function of the supply voltages.

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### **AC CHARACTERISTICS**

 $\mathsf{GND} = 0 \; \mathsf{V}; \, \mathsf{t_f} = \mathsf{t_f} \leq \mathsf{2.5ns}; \, \mathsf{C_L} = \mathsf{50pF}$ 

		CONDITION				LIMITS			
SYMBOL	PARAMETER	CONDITION	•	_	40 to +85 °	С	–40 to	+125 °C	UNIT
		V <sub>CC</sub> (V)	OTHER	MIN	TYP <sup>1</sup>	MAX	MIN	MAX	
		1.2			25				
		2.0	1		9	17		20	
<b>44</b>	Propagation delay	2.7	R <sub>L</sub> = ∞; C <sub>L</sub> = 50 pF		6	13		15	ns
t <sub>PHL</sub> /t <sub>PLH</sub>	$V_{is}$ to $V_{os}$	3.0 to 3.6	Figure 12		5 <sup>2</sup>	10		12	115
		4.5	] ~		4	9		10	
		6.0	1		3	7		8	
		1.2			100				
		2.0	$R_L = 1k\Omega;$		34	65		77	
t <sub>PZH</sub> /t <sub>PZL</sub> Turn-on time		2.7	$C_{L} = 50  pF$		25	48		56	ns
ΨZH/ΨZL	E to Vos	3.0 to 3.6	Figures 13		19 <sup>2</sup>	38		45	
		4.5	and 1	- 30	17	32		38	
		6.0	3-1	9-	13	25		29	
	Turn-on time S <sub>n</sub> to V <sub>os</sub>	1.2	16	-40	125				ns
		2.0	$R_L = 1k\Omega$ $C_L = 50 \text{ pF}$ Figures 13	200	43	82		97	
t <sub>PZH</sub> /t <sub>PZL</sub>		2.7			31	60		71	
¹PZH/¹PZL		3.0 to 3.6			24 <sup>2</sup>	48		57	
		4.5	and 1		21	41		48	
		6.0	ì		16	31		37	
		1.2			95				
		2.0	$R_L = 1k\Omega$		34	61		73	
t <sub>PHZ</sub> /t <sub>PLZ</sub>	Turn-off time	2.7	$C_L = 50 pF$		26	46		54	ns
PHZ/PLZ	E to Vos	3.0 to 3.6	Figures 13		20 <sup>2</sup>	37		44	113
		4.5	and 1		18	32		38	
		6.0	]		15	25		30	
		1.2			90				
		2.0	$R_L = 1k\Omega$		32	59		70	
t <sub>PHZ</sub> /t <sub>PLZ</sub>	Turn-off time	2.7	$C_{L} = 50  pF$		24	44		52	ns
4PHZ/4PLZ	Sn to Vos	3.0 to 3.6	Figures 13		19 <sup>2</sup>	36		42	
		4.5	and 1		17	31		36	
		6.0	]		14	24		28	

#### NOTES:

Unless otherwise stated, all typical values are measured at T<sub>amb</sub> = 25°C
 Typical values are measured at V<sub>CC</sub> = 3.3 V.

#### **ADDITIONAL AC CHARACTERISTICS**

Recommended conditions and typical values GND = 0 V;  $t_r$  =  $t_f \le 2.5 ns$ 

SYMBOL	PARAMETER	TYP.	UNIT	V <sub>CC</sub> (V)	V <sub>is(p-p)</sub> (V)	CONDITIONS
	Sine-wave distortion f = 1 kHz	0.80 0.40	%	3.0 6.0	2.75 5.50	$R_L$ = 10 kΩ; $C_L$ = 50 pf Figures 9 and 10
	Sine-wave distortion f = 10 kHz	2.40 1.20	%	3.0 6.0	2.75 5.50	$R_L$ = 10 kΩ; $C_L$ = 50 pf Figures 9 and 10
	Switch "OFF" signal feed through	-50 -50	dB	3.0 6.0	Note 1	$R_L$ = 600 $Ω$ ; $C_L$ = 50 pf; f= 1 MHz Figures 5 and 11
	Crosstalk between any two switches/multiplexers	-60 -60	dB	3.0 6.0	Note 1	$R_L = 600 \Omega$ ; $C_L = 50 pf$ ; $f = 1 MHz$ Figure 8
V <sub>(p-p)</sub>	Crosstalk voltage between enable or address input to any switch (peak-to-peak value)	110 120	mV	3.0 6.0		$R_L$ = 600 Ω; $C_L$ = 50 pf; f= 1 MHz ( $S_n$ or $\overline{E}$ , square wave between $V_{CC}$ and GND $t_r$ = $t_f$ = 6 ns) Figure 8
f <sub>max</sub>	Minimum frequency response (–3 dB)	180 200	MHz	3.0 6.0	Note 2	$R_L = 50 \Omega$ ; $C_L = 50 pF$ Figures 6, 8 and 9
C <sub>S</sub>	Maximum switch capacitance	5	pf		- The 3	2

#### **GENERAL NOTES:**

 $V_{is}$  is the input voltage at nY<sub>n</sub> or nZ terminal, whichever is assigned as an input.  $V_{OS}$  is the output voltage at nY<sub>n</sub> or nZ terminal, whichever is assigned as an output **NOTES:** 

- 1. Adjust input voltage  $V_{is}$  is 0 dBm level (0 dBm = 1 mW into 600  $\Omega$ ).
- 2. Adjust input voltage  $V_{is}$  is 0 dBm level at  $V_{OS}$  for 1 MHz (0 dBm = 1 mW into 50  $\Omega$ ).

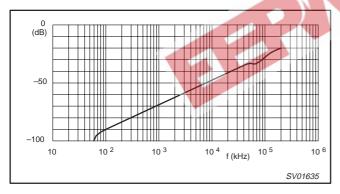


Figure 6. Typical switch "OFF" signal feed-through as a function of frequency.

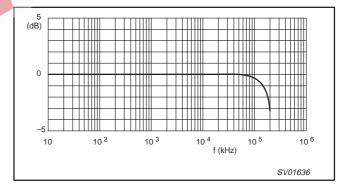


Figure 7. Typical frequency response.

#### **NOTES TO FIGURES 6 AND 7:**

Test conditions: V<sub>CC</sub> = 3.0 V; GND = 0 V; V<sub>EE</sub> = -3.0V; R<sub>L</sub> = 50  $\Omega$ ; R<sub>SOURCE</sub> = 1k $\Omega$ .

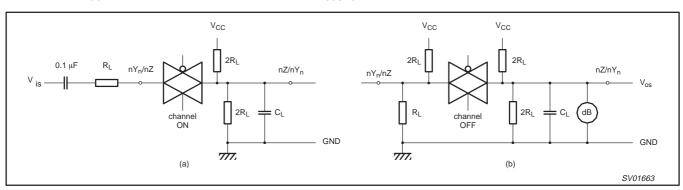


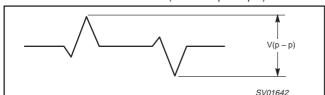
Figure 8. Test circuit for measuring crosstalk between any two switches.
(a) channel ON condition; (b) channel OFF condition.

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#### **NOTE TO FIGURE 8:**

The crosstalk is defined as follows (oscilloscope output):



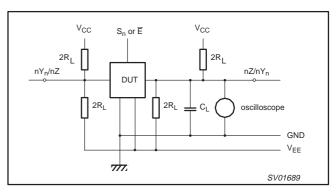


Figure 9. Test circuit for measuring crosstalk between control and any switch.

#### **NOTE TO FIGURE 9:**

**NOTE TO FIGURE 9:** Adjust input voltage to obtain 0 dBm at  $V_{OS}$  when  $F_{in}$  = 1 MHz. After set-up frequency of  $f_{in}$  is increased to obtain a reading of –3 dB at  $V_{OS}$ .

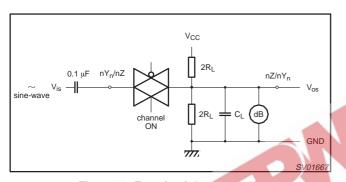


Figure 10. Test circuit for measuring minimum frequency response.

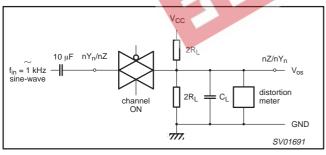


Figure 11. Test circuit for measuring sine-wave distortion.

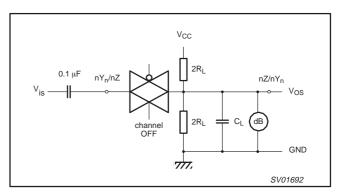


Figure 12. Test circuit for measuring switch "OFF" signal feed-through.

# Triple 2-channel analog multiplexer/demultiplexer

74LV4053

#### **WAVEFORMS**

 $V_M=1.5$  V at 2.7 V  $\leq$   $V_{CC}\leq$  3.6 V  $V_M=0.5\times V_{CC}$  at 2.7 V >  $V_{CC}>3.6$  V  $V_{OL}$  and  $V_{OH}$  are the typical output voltage drop that occur with the

 $\begin{array}{l} \text{V}_{\text{X}} = \text{V}_{\text{OL}} + 0.3 \text{ V at } 2.7 \text{ V} \leq \text{V}_{\text{CC}} \leq 3.6 \text{ V} \\ \text{V}_{\text{X}} = \text{V}_{\text{OL}} + 0.1 \times \text{V}_{\text{CC}} \text{ at } 2.7 \text{ V} > \text{V}_{\text{CC}} > 3.6 \text{ V} \\ \text{V}_{\text{Y}} = \text{V}_{\text{OH}} - 0.3 \text{ V at } 2.7 \text{ V} \leq \text{V}_{\text{CC}} \leq 3.6 \text{ V} \\ \text{V}_{\text{Y}} = \text{V}_{\text{OH}} - 0.1 \times \text{V}_{\text{CC}} \text{ at } 2.7 \text{ V} > \text{V}_{\text{CC}} > 3.6 \text{ V} \end{array}$ 

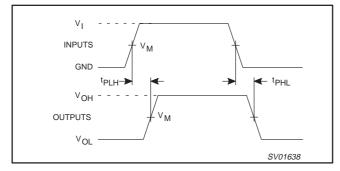


Figure 13. Input (Vis) to output (Vos) propagation delays.

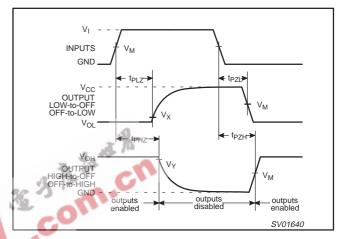


Figure 14. Turn-on and turn-off times for the inputs  $(S_n, \overline{E})$  to the output  $(V_{os})$ .

#### **TEST CIRCUIT**

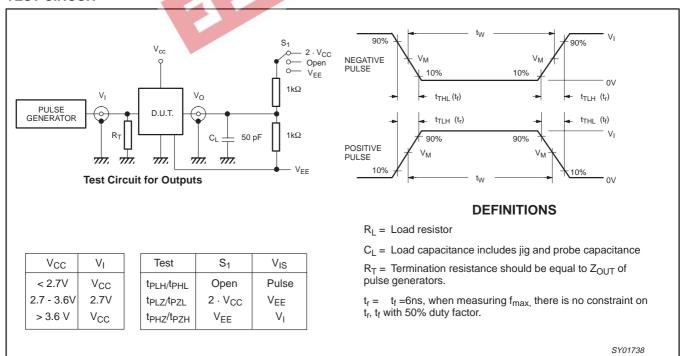


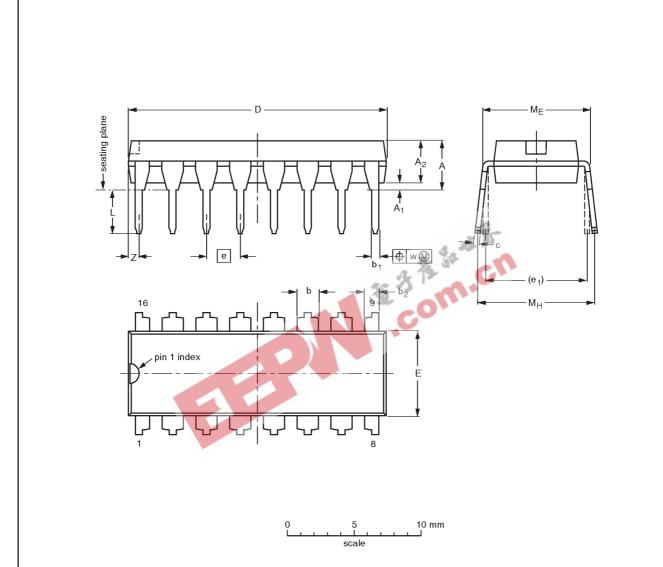
Figure 15. Load circuitry for switching times.

# Triple 2-channel analog multiplexer/demultiplexer

74LV4053

### DIP16: plastic dual in-line package; 16 leads (300 mil)

SOT38-4



#### DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A <sub>1</sub> min.	A <sub>2</sub> max.	b	b <sub>1</sub>	b <sub>2</sub>	С	D <sup>(1)</sup>	E <sup>(1)</sup>	е	e <sub>1</sub>	L	ME	Мн	w	Z <sup>(1)</sup> max.
mm	4.2	0.51	3.2	1.73 1.30	0.53 0.38	1.25 0.85	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	0.76
inches	0.17	0.020	0.13	0.068 0.051	0.021 0.015	0.049 0.033	0.014 0.009	0.77 0.73	0.26 0.24	0.10	0.30	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.030

#### Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

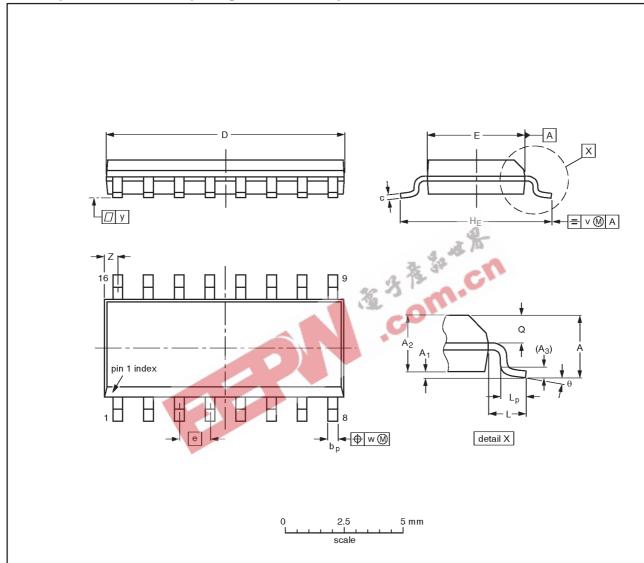
OUTLINE VERSION		REFER	EUROPEAN	ISSUE DATE	
	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE
SOT38-4					<del>92-11-17</del> 95-01-14

# Triple 2-channel analog multiplexer/demultiplexer

74LV4053

### SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



#### DIMENSIONS (inch dimensions are derived from the original mm dimensions)

							_											
UNIT	A max.	Α1	A <sub>2</sub>	<b>A</b> <sub>3</sub>	bp	С	D <sup>(1)</sup>	E <sup>(1)</sup>	е	HE	L	Lp	O	v	w	у	Z <sup>(1)</sup>	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	10.0 9.8	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	0.069	0.0098 0.0039		0.01		0.0098 0.0075	0.39 0.38	0.16 0.15	0.050	0.24 0.23	0.041	0.039 0.016	0.028 0.020	0.01	0.01	0.004	0.028 0.012	0°

#### Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

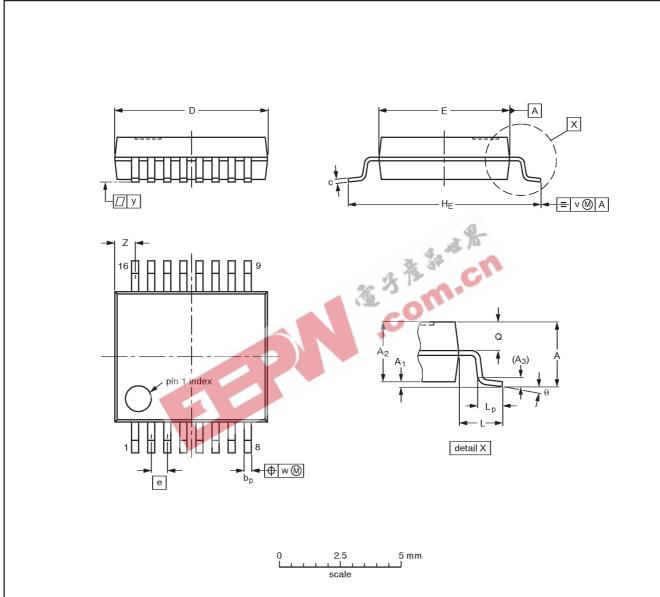
OUTLINE		REFER	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE
SOT109-1	076E07S	MS-012AC			<del>91-08-13</del> 95-01-23

# Triple 2-channel analog multiplexer/demultiplexer

74LV4053

### SSOP16: plastic shrink small outline package; 16 leads; body width 5.3 mm

SOT338-1



#### DIMENSIONS (mm are the original dimensions)

UNIT	A max.	Α1	A <sub>2</sub>	A <sub>3</sub>	рb	С	D <sup>(1)</sup>	E <sup>(1)</sup>	е	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
mm	2.0	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	6.4 6.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	1.00 0.55	8° 0°

#### Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

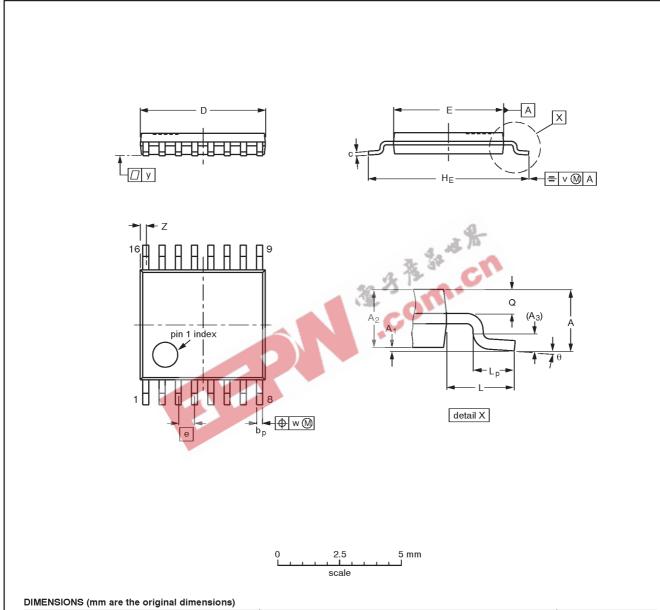
OUTLINE VERSION		REFER	EUROPEAN	ISSUE DATE		
	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT338-1		MO-150AC				<del>94-01-14</del> 95-02-04

# Triple 2-channel analog multiplexer/demultiplexer

74LV4053

### TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1



UNIT	A max.	Α1	A <sub>2</sub>	<b>A</b> <sub>3</sub>	bp	c	D <sup>(1)</sup>	E <sup>(2)</sup>	е	HE	L	Lp	Ø	v	w	у	Z <sup>(1)</sup>	θ
mm	1.10	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1.0	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.40 0.06	8° 0°

#### Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	EIAJ	PROJECTION	1990E DATE
SOT403-1		MO-153			<del>-94-07-12-</del> 95-04-04

# Triple 2-channel analog multiplexer/demultiplexer

74LV4053

#### **NOTES**



### Triple 2-channel analog multiplexer/demultiplexer

74LV4053



Data Sheet Identification	Product Status	Definition
Objective Specification	Formative or in Design	This data sheet contains the design target or goal specifications for product development. Specifications may change in any manner without notice.
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